

Day : Wednesday

Date: 11/8/2006

Time: 14:09:26

PALM INTRANET

Inventor Name Search Result

Your Search was:

Last Name = DWILINSKI

First Name = ROBERT

| Application# | Patent# | Status | Date Filed | Title | Inventor Name |
|----------------------|----------------|--------|------------|---|-------------------|
| <u>10479856</u> | <u>7081162</u> | 150 | 06/04/2004 | METHOD OF MANUFACTURING BULK SINGLE CRYSTAL OF GALLIUM NITRIDE | DWILINSKI, ROBERT |
| *10479857 | Not Issued | 71 | 06/09/2004 | Method for forming gallium-containing nitride bulk single crystal on heterogenous substrate | DWILINSKI, ROBERT |
| <u>10479858</u> | Not Issued | 93 | 08/31/2004 | METHOD AND EQUIPMENT FOR MANUFACTURING ALUMINUM NITRIDE BULK SINGLE CRYSTAL | DWILINSKI, ROBERT |
| <u>10493594</u> | Not Issued | 71 | 04/26/2004 | Light emitting element structure using nitride bulk single crystal layer | DWILINSKI, ROBERT |
| <u>10493746</u> | <u>7057211</u> | 150 | 04/26/2004 | NITRIDE SEMICONDUCTOR LASER DEVICE AND MANUFACTURING METHOD THEREFOR | DWILINSKI, ROBERT |
| <u>10493747</u> | <u>7132730</u> | 150 | 04/26/2004 | BULK NITRIDE MONO-CRYSTAL INCLUDING SUBSTRATE FOR EPITAXY | DWILINSKI, ROBERT |
| <u>10514429</u> | Not Issued | 20 | 07/12/2005 | Phosphor single crystal substrate and method for preparing the same, and nitride semiconductor component using the same | DWILINSKI, ROBERT |
| <u>10514638</u> | Not Issued | 30 | 08/22/2005 | Light emitting device structure having nitride bulk single crystal layer | DWILINSKI, ROBERT |
| <u>10514639</u> | Not Issued | 25 | 08/30/2005 | Bulk single crystal production facility employing supercritical ammonia | DWILINSKI, ROBERT |
| <u>10519141</u> | Not Issued | 30 | 12/27/2004 | Process for obtaining of bulk monocrystalline gallium- | DWILINSKI, ROBERT |

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|--------------------------|-------------------------|-----|------------|---|--------------------------|
| | | | | containing nitride | |
| 10519501 | Not Issued | 41 | 12/27/2004 | Nitride semiconductor laser device and a method for improving its performance | DWILINSKI, ROBERT |
| 10537804 | Not Issued | 25 | 06/07/2005 | Process for obtaining bulk mono-crystalline gallium-containing nitride | DWILINSKI, ROBERT |
| 10538349 | Not Issued | 25 | 06/10/2005 | Improved process for obtaining bulk mono-crystalline gallium-containing nitride | DWILINSKI, ROBERT |
| 10538407 | Not Issued | 20 | 06/10/2005 | Substrate for epitaxy and method of preparing the same | DWILINSKI, ROBERT |
| 10538654 | Not Issued | 30 | 06/10/2005 | Template type substrate and a method of preparing the same | DWILINSKI, ROBERT |
| 10147318 | 6656615 | 150 | 05/17/2002 | BULK MONOCRYSTALLINE GALLIUM NITRIDE | DWILINSKI, ROBERT TOMASZ |
| 10147319 | Not Issued | 95 | 05/17/2002 | PROCESS AND APPARATUS FOR OBTAINING BULK MONOCRYSTALLINE GALLIUM-CONTAINING NITRIDE | DWILINSKI, ROBERT TOMASZ |
| 10682891 | Not Issued | 71 | 10/14/2003 | Bulk monocrystalline gallium nitride | DWILINSKI, ROBERT TOMASZ |

Inventor Search Completed: No Records to Display.

| | | | |
|---------------------------------|--|-------------------------------------|---------------------------------------|
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| | <input type="text" value="Dwilinski"/> | <input type="text" value="Robert"/> | |

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PALM INTRANET

Inventor Name Search Result

Your Search was:

Last Name = DORADZINSKI

First Name = ROMAN

| Application# | Patent# | Status | Date Filed | Title | Inventor Name |
|--------------------------|-------------------------|--------|------------|---|--------------------|
| 10479856 | 7081162 | 150 | 06/04/2004 | METHOD OF MANUFACTURING BULK SINGLE CRYSTAL OF GALLIUM NITRIDE | DORADZINSKI, ROMAN |
| 10479857 | Not Issued | 41 | 06/09/2004 | Method for forming gallium-containing nitride bulk single crystal on heterogenous substrate | DORADZINSKI, ROMAN |
| 10479858 | Not Issued | 93 | 08/31/2004 | METHOD AND EQUIPMENT FOR MANUFACTURING ALUMINUM NITRIDE BULK SINGLE CRYSTAL | DORADZINSKI, ROMAN |
| 10493594 | Not Issued | 71 | 04/26/2004 | Light emitting element structure using nitride bulk single crystal layer | DORADZINSKI, ROMAN |
| 10493746 | 7057211 | 150 | 04/26/2004 | NITRIDE SEMICONDUCTOR LASER DEVICE AND MANUFACTURING METHOD THEREFOR | DORADZINSKI, ROMAN |
| 10493747 | 7132730 | 150 | 04/26/2004 | BULK NITRIDE MONO-CRYSTAL INCLUDING SUBSTRATE FOR EPITAXY | DORADZINSKI, ROMAN |
| 10514429 | Not Issued | 20 | 07/12/2005 | Phosphor single crystal substrate and method for preparing the same, and nitride semiconductor component using the same | DORADZINSKI, ROMAN |
| 10514638 | Not Issued | 30 | 08/22/2005 | Light emitting device structure having nitride bulk single crystal layer | DORADZINSKI, ROMAN |
| 10514639 | Not Issued | 25 | 08/30/2005 | Bulk single crystal production facility employing supercritical ammonia | DORADZINSKI, ROMAN |
| 10519141 | Not | 30 | 12/27/2004 | Process for obtaining of bulk | DORADZINSKI, |

| | | | | | |
|--------------------------|-------------------------|-----|------------|---|--------------------------|
| | Issued | | | monocrystalline gallium-containing nitride | ROMAN |
| 10519501 | Not Issued | 41 | 12/27/2004 | Nitride semiconductor laser device and a method for improving its performance | DORADZINSKI, ROMAN |
| 10537804 | Not Issued | 25 | 06/07/2005 | Process for obtaining bulk mono-crystalline gallium-containing nitride | DORADZINSKI, ROMAN |
| 10538349 | Not Issued | 25 | 06/10/2005 | Improved process for obtaining bulk mono-crystalline gallium-containing nitride | DORADZINSKI, ROMAN |
| 10538407 | Not Issued | 20 | 06/10/2005 | Substrate for epitaxy and method of preparing the same | DORADZINSKI, ROMAN |
| 10538654 | Not Issued | 30 | 06/10/2005 | Template type substrate and a method of preparing the same | DORADZINSKI, ROMAN |
| 10147318 | 6656615 | 150 | 05/17/2002 | BULK MONOCRYSTALLINE GALLIUM NITRIDE | DORADZINSKI, ROMAN MAREK |
| 10147319 | Not Issued | 95 | 05/17/2002 | PROCESS AND APPARATUS FOR OBTAINING BULK MONOCRYSTALLINE GALLIUM-CONTAINING NITRIDE | DORADZINSKI, ROMAN MAREK |
| 10479807 | Not Issued | 100 | 12/05/2003 | PROCESS AND APPARATUS FOR OBTAINING BULK MONOCRYSTALLINE GALLIUM-CONTAINING NITRIDE | DORADZINSKI, ROMAN MAREK |
| 10682891 | Not Issued | 71 | 10/14/2003 | Bulk monocrystalline gallium nitride | DORADZINSKI, ROMAN MAREK |

Inventor Search Completed: No Records to Display.

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|---------------------------------|--|------------------------------------|---------------------------------------|
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| | <input type="text" value="Doradzinski"/> | <input type="text" value="Roman"/> | |

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Day : Wednesday

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PALM INTRANET

Inventor Name Search Result

Your Search was:

Last Name = GARCZYNSKI

First Name = JERZY

| Application# | Patent# | Status | Date Filed | Title | Inventor Name |
|-----------------|------------|--------|------------|---|-------------------|
| <u>10147318</u> | 6656615 | 150 | 05/17/2002 | BULK MONOCRYSTALLINE GALLIUM NITRIDE | GARCZYNSKI, JERZY |
| <u>10147319</u> | Not Issued | 95 | 05/17/2002 | PROCESS AND APPARATUS FOR OBTAINING BULK MONOCRYSTALLINE GALLIUM-CONTAINING NITRIDE | GARCZYNSKI, JERZY |
| <u>10479807</u> | Not Issued | 100 | 12/05/2003 | PROCESS AND APPARATUS FOR OBTAINING BULK MONOCRYSTALLINE GALLIUM-CONTAINING NITRIDE | GARCZYNSKI, JERZY |
| <u>10479856</u> | 7081162 | 150 | 06/04/2004 | METHOD OF MANUFACTURING BULK SINGLE CRYSTAL OF GALLIUM NITRIDE | GARCZYNSKI, JERZY |
| <u>10479857</u> | Not Issued | 41 | 06/09/2004 | Method for forming gallium-containing nitride bulk single crystal on heterogenous substrate | GARCZYNSKI, JERZY |
| <u>10479858</u> | Not Issued | 93 | 08/31/2004 | METHOD AND EQUIPMENT FOR MANUFACTURING ALUMINUM NITRIDE BULK SINGLE CRYSTAL | GARCZYNSKI, JERZY |
| <u>10493594</u> | Not Issued | 71 | 04/26/2004 | Light emitting element structure using nitride bulk single crystal layer | GARCZYNSKI, JERZY |
| <u>10493746</u> | 7057211 | 150 | 04/26/2004 | NITRIDE SEMICONDUCTOR LASER DEVICE AND MANUFACTURING METHOD THEREFOR | GARCZYNSKI, JERZY |
| <u>10493747</u> | 7132730 | 150 | 04/26/2004 | BULK NITRIDE MONO-CRYSTAL INCLUDING SUBSTRATE FOR EPITAXY | GARCZYNSKI, JERZY |

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|--------------------------|------------|----|------------|---|-------------------|
| 10514429 | Not Issued | 20 | 07/12/2005 | Phosphor single crystal substrate and method for preparing the same, and nitride semiconductor component using the same | GARCZYNSKI, JERZY |
| 10514638 | Not Issued | 30 | 08/22/2005 | Light emitting device structure having nitride bulk single crystal layer | GARCZYNSKI, JERZY |
| 10514639 | Not Issued | 25 | 08/30/2005 | Bulk single crystal production facility employing supercritical ammonia | GARCZYNSKI, JERZY |
| 10519141 | Not Issued | 30 | 12/27/2004 | Process for obtaining of bulk monocrystalline gallium-containing nitride | GARCZYNSKI, JERZY |
| 10519501 | Not Issued | 41 | 12/27/2004 | Nitride semiconductor laser device and a method for improving its performance | GARCZYNSKI, JERZY |
| 10537804 | Not Issued | 25 | 06/07/2005 | Process for obtaining bulk monocrystalline gallium-containing nitride | GARCZYNSKI, JERZY |
| 10538349 | Not Issued | 25 | 06/10/2005 | Improved process for obtaining bulk mono-crystalline gallium-containing nitride | GARCZYNSKI, JERZY |
| 10538407 | Not Issued | 20 | 06/10/2005 | Substrate for epitaxy and method of preparing the same | GARCZYNSKI, JERZY |
| 10538654 | Not Issued | 30 | 06/10/2005 | Template type substrate and a method of preparing the same | GARCZYNSKI, JERZY |
| 10682891 | Not Issued | 71 | 10/14/2003 | Bulk monocrystalline gallium nitride | GARCZYNSKI, JERZY |

Inventor Search Completed: No Records to Display.

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 PALM INTRANET**Inventor Name Search Result**

Your Search was:

Last Name = SIERPUTOWSKI

First Name = LESZEK

| Application# | Patent# | Status | Date Filed | Title | Inventor Name |
|--------------------------|---------------|--------|------------|---|----------------------------|
| 10519141 | Not Issued | 30 | 12/27/2004 | Process for obtaining of bulk monocrystalline gallium- containing nitride | SIERPUTOWSKI, LESZEK P. |

Inventor Search Completed: No Records to Display.

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|---------------------------------|---|-------------------------------------|---------------------------------------|
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| | <input type="text" value="Sierputowski"/> | <input type="text" value="Leszek"/> | |

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PALM INTRANET

Inventor Name Search Result

Your Search was:

Last Name = KANBARA

First Name = YASUO

| Application# | Patent# | Status | Date Filed | Title | Inventor Name |
|--------------------------|-------------------------|--------|------------|--|----------------|
| 10147318 | 6656615 | 150 | 05/17/2002 | BULK MONOCRYSTALLINE GALLIUM NITRIDE | KANBARA, YASUO |
| 10147319 | Not Issued | 95 | 05/17/2002 | PROCESS AND APPARATUS FOR OBTAINING BULK MONOCRYSTALLINE GALLIUM-CONTAINING NITRIDE | KANBARA, YASUO |
| 10192246 | 7042830 | 150 | 07/09/2002 | PHASE-CHANGE OPTICAL INFORMATION RECORDING MEDIUM, AND OPTICAL INFORMATION RECORDING AND REPRODUCING APPARATUS AND METHOD FOR THE SAME | KANBARA, YASUO |
| 10479807 | Not Issued | 100 | 12/05/2003 | PROCESS AND APPARATUS FOR OBTAINING BULK MONOCRYSTALLINE GALLIUM-CONTAINING NITRIDE | KANBARA, YASUO |
| 10479856 | 7081162 | 150 | 06/04/2004 | METHOD OF MANUFACTURING BULK SINGLE CRYSTAL OF GALLIUM NITRIDE | KANBARA, YASUO |
| 10479857 | Not Issued | 41 | 06/09/2004 | Method for forming gallium-containing nitride bulk single crystal on heterogenous substrate | KANBARA, YASUO |
| 10479858 | Not Issued | 93 | 08/31/2004 | METHOD AND EQUIPMENT FOR MANUFACTURING ALUMINUM NITRIDE BULK SINGLE CRYSTAL | KANBARA, YASUO |
| 10493594 | Not Issued | 71 | 04/26/2004 | Light emitting element structure using nitride bulk single crystal layer | KANBARA, YASUO |
| 10493746 | 7057211 | 150 | 04/26/2004 | NITRIDE SEMICONDUCTOR | KANBARA, |

| | | | | | |
|-----------------|----------------|-----|------------|--|-------------------|
| | | | | LASER DEVICE AND MANUFACTURING METHOD THEREFOR | YASUO |
| <u>10493747</u> | <u>7132730</u> | 150 | 04/26/2004 | BULK NITRIDE MONO- CRYSTAL INCLUDING SUBSTRATE FOR EPITAXY | KANBARA, YASUO |
| <u>10514429</u> | Not Issued | 20 | 07/12/2005 | Phosphor single crystal substrate and method for preparing the same, and nitride semiconductor component using the same | KANBARA, YASUO |
| <u>10514638</u> | Not Issued | 30 | 08/22/2005 | Light emitting device structure having nitride bulk single crystal layer | KANBARA, YASUO |
| <u>10514639</u> | Not Issued | 25 | 08/30/2005 | Bulk single crystal production facility employing supercritical ammonia | KANBARA, YASUO |
| <u>10519141</u> | Not Issued | 30 | 12/27/2004 | Process for obtaining of bulk monocrystalline gallium- containing nitride | KANBARA, YASUO |
| <u>10519501</u> | Not Issued | 41 | 12/27/2004 | Nitride semiconductor laser device and a method for improving its performance | KANBARA, YASUO |
| <u>10537804</u> | Not Issued | 25 | 06/07/2005 | Process for obtaining bulk mono- crystalline gallium-containing nitride | KANBARA, YASUO |
| <u>10538349</u> | Not Issued | 25 | 06/10/2005 | Improved process for obtaining bulk mono-crystalline gallium- containing nitride | KANBARA, YASUO |
| <u>10538407</u> | Not Issued | 20 | 06/10/2005 | Substrate for epitaxy and method of preparing the same | KANBARA, YASUO |
| <u>10538654</u> | Not Issued | 30 | 06/10/2005 | Template type substrate and a method of preparing the same | KANBARA, YASUO |
| <u>10682891</u> | Not Issued | 71 | 10/14/2003 | Bulk monocrystalline gallium nitride | KANBARA, YASUO |

Inventor Search Completed: No Records to Display.

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| | <input type="text" value="Kanbara"/> | <input type="text" value="Yasuo"/> | |

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